hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, Washington, D.C. 20231, on August 30, 2002.

Reg. No.: 29,182

John J. Kelly, Jr.

Examiner: Alonzo Chambliss

Art Unit: 2827

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants:

K. TATSUMI et al.

Serial No.:

09/632,910

Filed

August 4, 2000

For

SEMICONDUCTOR DEVICE PROVIDED WITH LOW MELTING

POINT METAL BUMPS AND PROCESS FOR PRODUCING

SAME

Commissioner for Patents Washington, D.C. 20231

AMENDMENT UNDER RULE 116

SIR:

Kindly amend the claims of the above-iden ified patent application as follows.

## In The Title

Cancel the current title of the invention and replace it with the following new title.

--METHOD FOR FABRICATING A SEMICONDUCTOR DEVICE PROVIDED WITH LOW MELTING POINT METAL BUMPS--.

## In The Claims

--16. A process for producing a (Amended) semiconductor device to be mounted on a substrate by flip chip bonding comprising electrodes formed on a semiconductor chip, and bumps each consisting of a spherically formed metal ball having a given size, and adhesive bonded to the electrodes (8) for the attachment of the bumps, wherein each electrode (8) includes a layer of an